

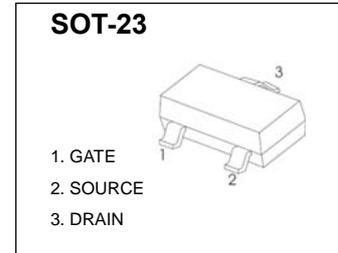


DONGGUAN NANJING ELECTRONICS LTD.,

SOT-23 Plastic-Encapsulate MOSFETS

NJMN0040 N-Channel Enhancement Mode Field Effect Transistor

$V_{(BR)DSS}$	$R_{DS(on)MAX}$	I_D
40V	45mΩ@ 10	3.5A
	65mΩ@4.5V	
	82mΩ@2.5V	



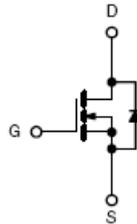
FEATURE

- High dense cell design for extremely low $R_{DS(ON)}$
- Exceptional on-resistance and maximum DC current capability

APPLICATION

- Load/Power Switching
- Interfacing Switching

Equivalent Circuit



Maximum ratings ($T_a=25^{\circ}C$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	40	V
Gate-Source Voltage	V_{GS}	±20	V
Continuous Drain Current	I_D	3.5	A
Drain Current-Pulsed ^①	I_{DM}	18	A
Power Dissipation	P_D	1250	mW
Thermal Resistance from Junction to Ambient	$R_{\theta JA}$	100	$^{\circ}C/W$
Operation Junction and Storage Temperature Range	T_J, T_{STG}	-55~+150	$^{\circ}C$

MOSFET ELECTRICAL CHARACTERISTICS

$T_a=25\text{ }^\circ\text{C}$ unless otherwise specified

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Off Characteristics						
Drain-source breakdown voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = 250\mu A$	40			V
Zero gate voltage drain current	I_{DSS}	$V_{DS} = 32V, V_{GS} = 0V, T_J = 25\text{ }^\circ\text{C}$			1	μA
		$V_{DS} = 32V, V_{GS} = 0V, T_J = 125\text{ }^\circ\text{C}$			1	mA
Gate-source leakage current	I_{GSS}	$V_{GS} = \pm 20V, V_{DS} = 0V$			± 100	nA
On characteristics						
Drain-source on-resistance ^②	$R_{DS(on)}$	$V_{GS} = 10V, I_D = 3.5A$		36	45	m Ω
		$V_{GS} = 4.5V, I_D = 3.0A$		56	65	m Ω
		$V_{GS} = 2.5V, I_D = 2.5A$			82	m Ω
Forward transconductance	g_{FS}	$V_{DS} = 5V, I_D = 3.5A$	8			S
Gate threshold voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250\mu A$	1.0	1.4	2.5	V
Dynamic Characteristics ^③						
Input capacitance	C_{iss}	$V_{DS} = 20V, V_{GS} = 0V, f = 1MHz$		315	820	pF
Output capacitance	C_{oss}			69		pF
Reverse transfer capacitance	C_{rss}			39		pF
Gate resistance	R_g	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$		3.6		Ω
Switching Characteristics ^③						
Turn-on delay time	$t_{d(on)}$	$V_{GS} = 10V, V_{DS} = 20V, I_D = 1A, R_{GEN} = 6\Omega$		5	10	ns
Turn-on rise time	t_r			12	20	ns
Turn-off delay time	$t_{d(off)}$			20	25	ns
Turn-off fall time	t_f			15	20	ns
Total Gate Charge	Q_g	$V_{DS} = 20V, I_D = 3.5A, V_{GS} = 0V$		6.4	10	nC
Gate-Source Charge	Q_{gs}			0.7		nC
Gate-Drain Charge	Q_{gd}			2.1		nC
Drain-source diode characteristics and maximum ratings						
Diode forward voltage ^②	V_{SD}	$I_S = 1A, V_{GS} = 0V$		0.8	1.2	V
Continuous drain-source diode forward current	I_S				1.0	A
Pulsed drain-source diode forward current ^①	I_{SM}				18	A

Note :

1. Repetitive Rating : Pulse width limited by maximum junction temperature.
2. Pulse Test : Pulse Width $\leq 300\mu s$, Duty Cycle $\leq 2\%$.
3. Guaranteed by design, not subject to production testing.

Typical Characteristics

Fig1. $I_D - V_{DS}$

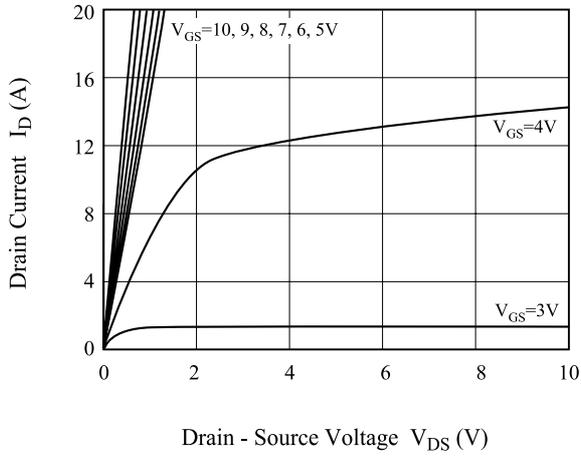


Fig2. $R_{DS(ON)} - I_D$

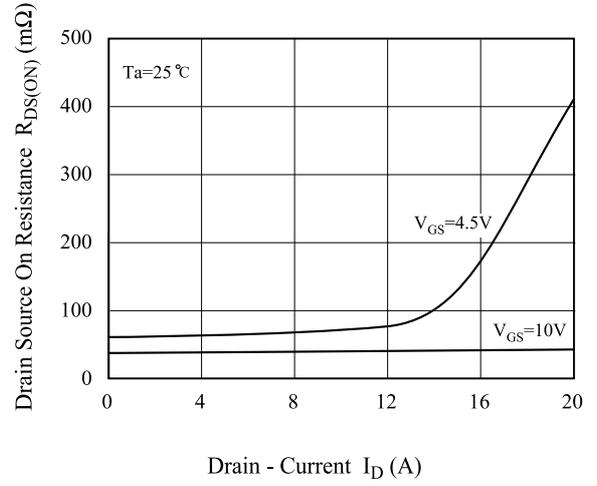


Fig3. $I_D - V_{GS}$

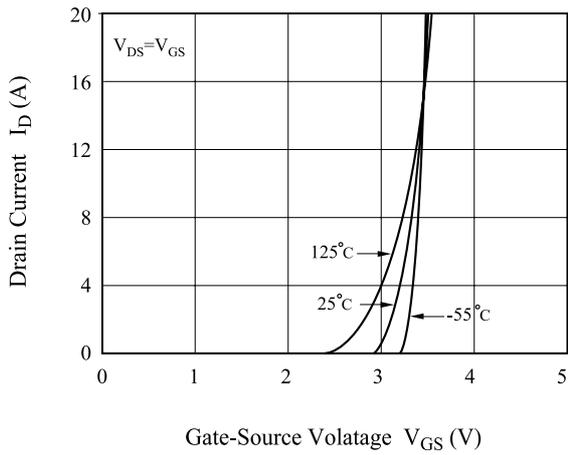


Fig4. $R_{DS(ON)} - T_j$

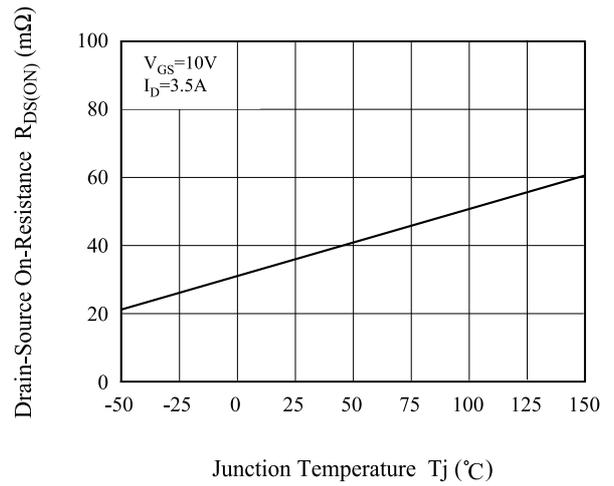


Fig5. $V_{th} - T_j$

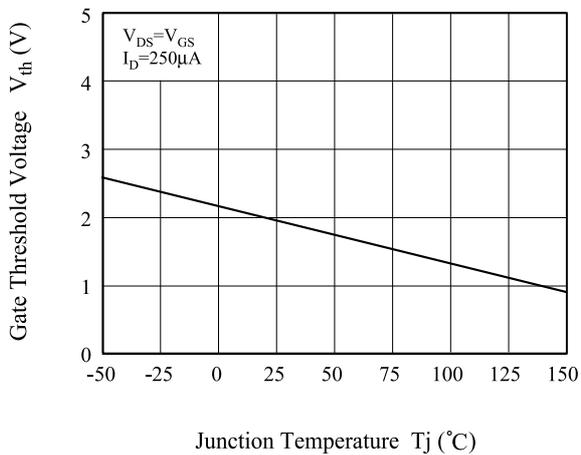
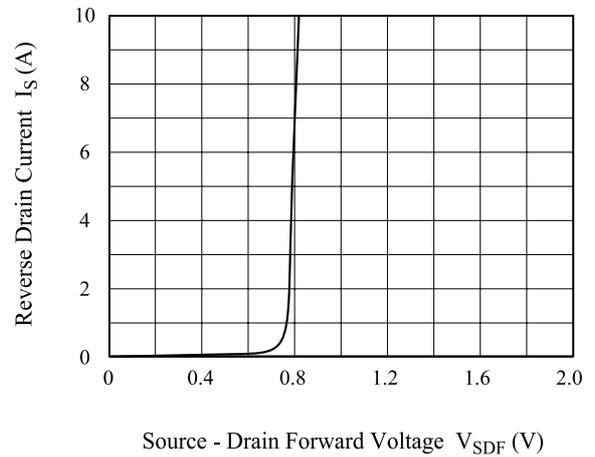


Fig6. $I_S - V_{SDF}$



Typical Characteristics

Fig7. $V_{GS} - Q_g$

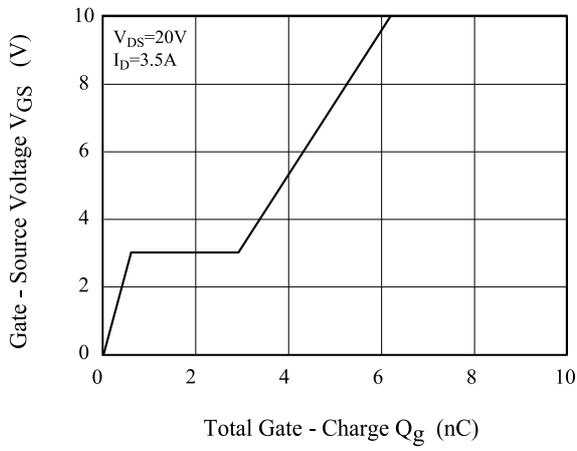


Fig8. $C - V_{DS}$

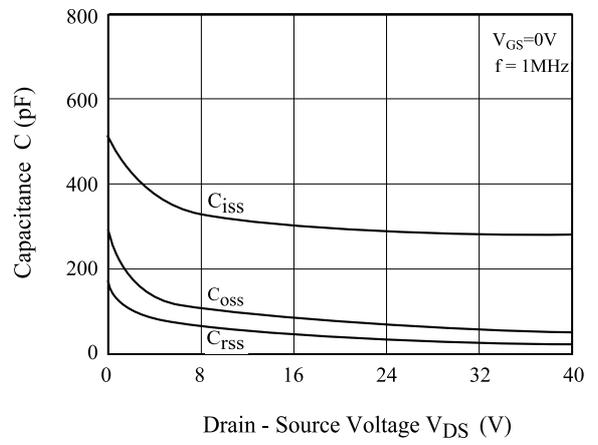


Fig9. Safe Operation Area

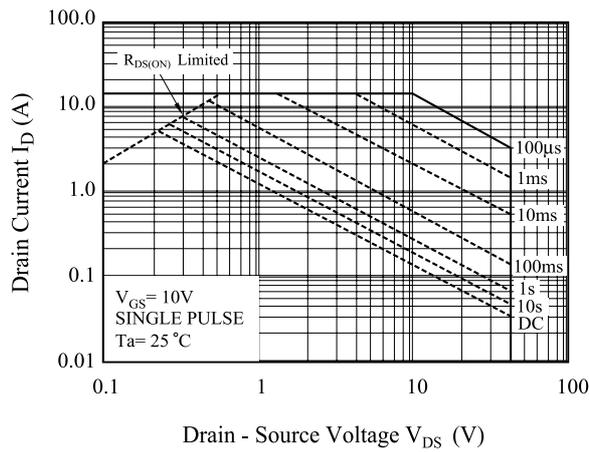
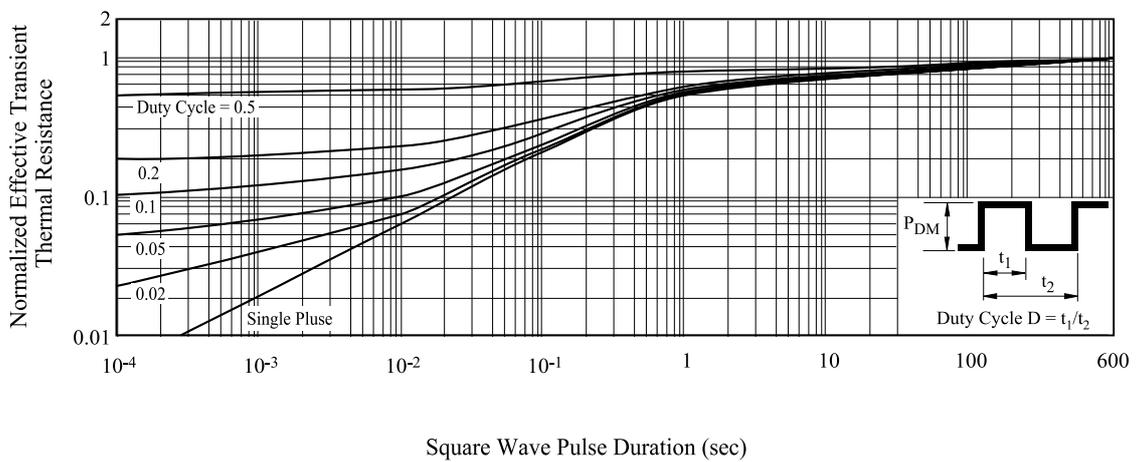
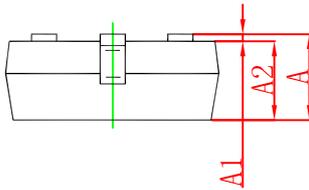
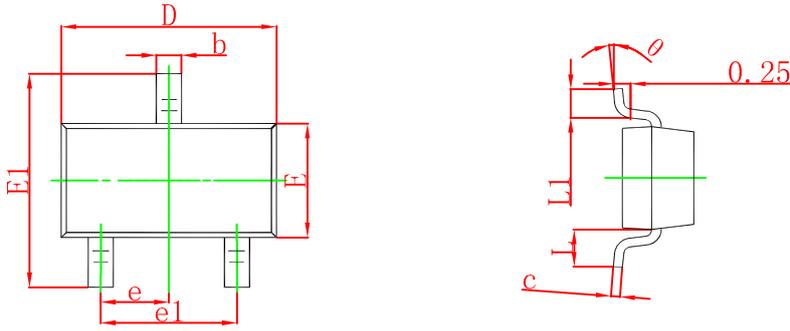


Fig10. Transient Thermal Response Curve

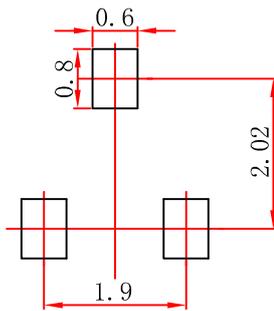


SOT-23 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP		0.037 TYP	
e1	1.800	2.000	0.071	0.079
L	0.550 REF		0.022 REF	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°

SOT-23 Suggested Pad Layout

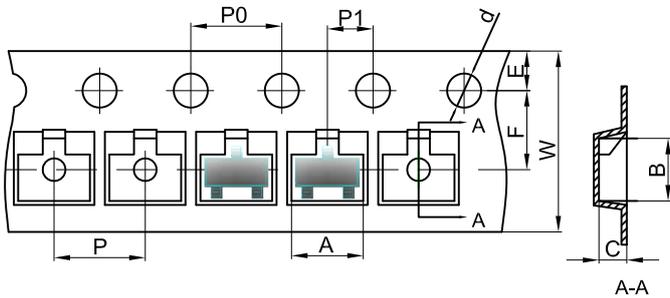


Note:

1. Controlling dimension: in millimeters.
2. General tolerance: $\pm 0.05\text{mm}$.
3. The pad layout is for reference purposes only.

SOT-23 Tape and Reel

SOT-23 Embossed Carrier Tape



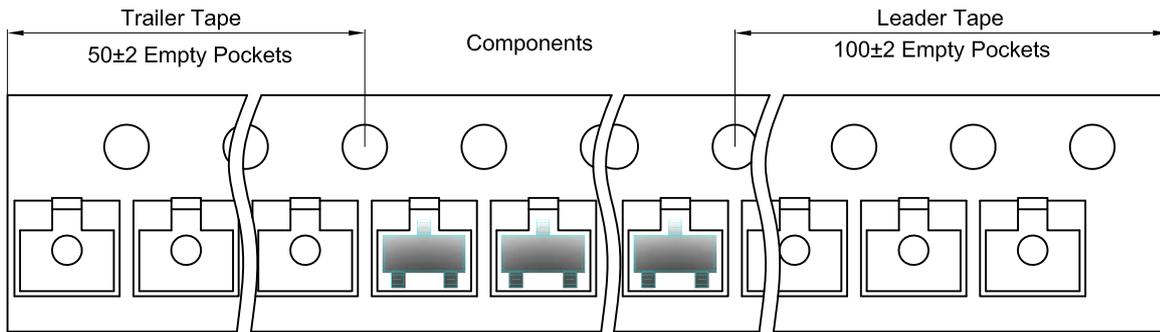
Packaging Description:

SOT-23 parts are shipped in tape. The carrier tape is made from a dissipative (carbon filled) polycarbonate resin. The cover tape is a multilayer film (Heat Activated Adhesive in nature) primarily composed of polyester film, adhesive layer, sealant, and anti-static sprayed agent. These reeled parts in standard option are shipped with 3,000 units per 7" or 17.8cm diameter reel. The reels are clear in color and is made of polystyrene plastic (anti-static coated).

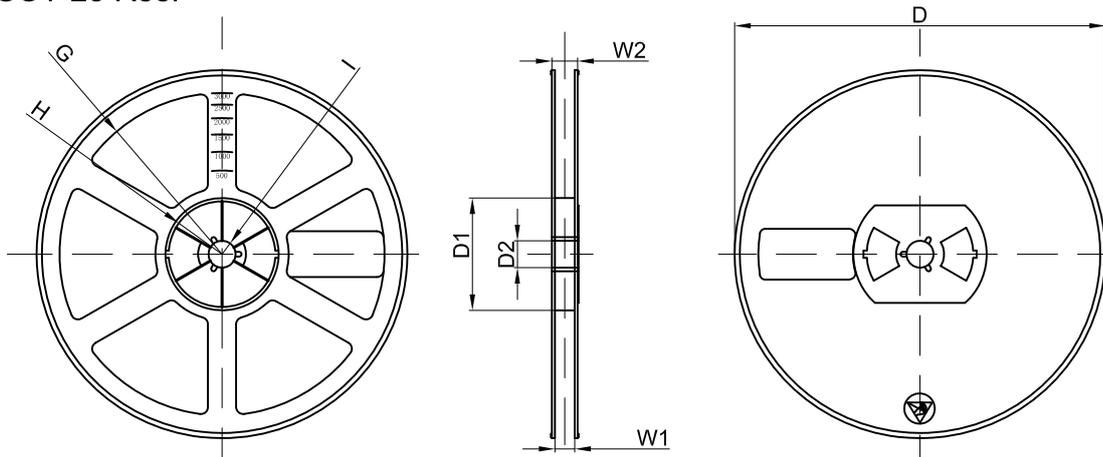
Dimensions are in millimeter

Pkg type	A	B	C	d	E	F	P0	P	P1	W
SOT-23	3.15	2.77	1.22	Ø1.50	1.75	3.50	4.00	4.00	2.00	8.00

SOT-23 Tape Leader and Trailer



SOT-23 Reel



Dimensions are in millimeter

Reel Option	D	D1	D2	G	H	I	W1	W2
7"Dia	Ø178.00	54.40	13.00	R78.00	R25.60	R6.50	9.50	12.30

REEL	Reel Size	Box	Box Size(mm)	Carton	Carton Size(mm)	G.W.(kg)
3000 pcs	7 inch	30,000 pcs	203×203×195	120,000 pcs	438×438×220	